VS-MBR2080CT-M3, VS-MBR2090CT-M3, VS-MBR20100CT-M3

Vishay Semiconductors

ROHS COMPLIANT

HALOGEN

FREE

High Performance Schottky Rectifier, 2 x 10 A



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PRIMARY CHARACTERISTICS				
I _{F(AV)}	2 x 10 A			
V _R	80 V, 90 V, 100 V			
V _F at I _F	0.70 V			
I _{RM} max.	6 mA at 125 °C			
T _J max.	150 °C			
E _{AS}	24 mJ			
Package	TO-220AB 3L			
Circuit configuration	Common cathode			

FEATURES

- 150 °C T_J operation
- Low forward voltage drop
- · High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

This center tap Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
I _{F(AV)}	Rectangular waveform (per device)	20	А		
I _{FRM}	T _C = 133 °C per leg	20	А		
V _{RRM}		80/100	V		
I _{FSM}	t _p = 5 μs sine	850	А		
V _F	10 A _{pk} , T _J = 125 °C	0.70	V		
TJ	Range	-65 to +150	°C		

VOLTAGE RATINGS						
PARAMETER SYMBOL MBR2080CT-M3 MBR2090CT-M3 MBR20100CT-M3 UNITS						
Maximum DC reverse voltage	V _R	80	90	100	М	
Maximum working peak reverse voltage	V _{RWM}	80	90	100	v	

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CON	TEST CONDITIONS		UNITS	
Maximum average per leg	1	- I _{F(AV)} T _C = 133 °C, rated V _R $-$		10		
forward current per device	IF(AV)			20		
Peak repetitive forward current per leg	I _{FRM}	Rated V _R , square wave, 20 kHz, T _C = 133 °C		20		
Non-repetitive peak surge current	I _{FSM}	5 µs sine or 3 µs rect. pulse	Following any rated load condition and with rated V _{RRM} applied	850 A		
	-	Surge applied at rated load conditions halfwave, single phase, 60 Hz		150		
Peak repetitive reverse surge current	I _{RRM}	2.0 μs, 1.0 kHz		0.5		
Non-repetitive avalanche energy per le	E _{AS}	T _J = 25 °C, I _{AS} = 2 A, L = 12	mH	24	mJ	

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ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS	
		10 A	T _{.1} = 25 °C	0.80		
Maximum fanward voltage drep	V _{FM} ⁽¹⁾	20 A	1j=25 C	0.95	v	
Maximum forward voltage drop	VFM (1)	10 A	T 105 %C	0.70		
		20 A	T _J = 125 °C	0.85		
Maximum instantaneous reverse current	I _{RM} ⁽¹⁾	T _J = 25 °C	Dated DC valtage	0.10	mA	
Maximum instantaneous reverse current		T _J = 125 °C	Rated DC voltage	6		
Threshold voltage	V _{F(TO)}	T T maximum		0.433	V	
Forward slope resistance	r _t	$T_J = T_J maximum$		15.8	mΩ	
Maximum junction capacitance	CT	V_R = 5 V_{DC} (test signal range 100 kHz to 1 MHz) 25 °C		400	pF	
Typical series inductance	L _S	Measured from top of terminal to mounting plane		8.0	nH	
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs	

Note

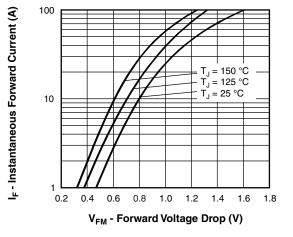
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 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECI	THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum junction temperature range		TJ		-65 to +150	°C		
Maximum storage tempe	rature range	T _{Stg}		-65 to +175	C		
Maximum thermal resista junction to case per leg	ince,	R _{thJC}	DC operation	2.0			
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased (Only for TO-220)	0.50	°C/W		
Maximum thermal resista junction to ambient	Maximum thermal resistance, junction to ambient		DC operation (For D ² PAK and TO-262)	50			
Approvimate weight				2	g		
Approximate weight				0.07	oz.		
Mounting torque	minimum			6 (5)	kg∙ cm		
Mounting torque maximum				12 (10)	(lbf · in)		
Marking device			Case style TO-220AB 3L	MBR20 MBR20 MBR20	090CT		

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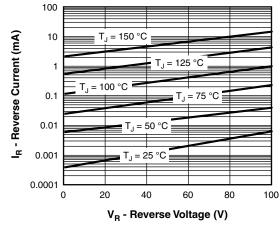


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

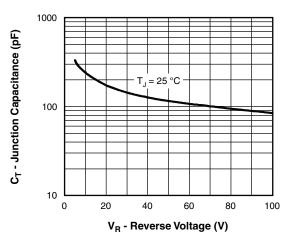


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

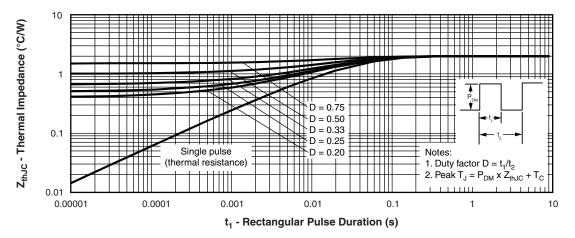
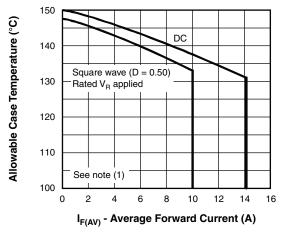
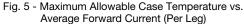


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics (Per Leg)

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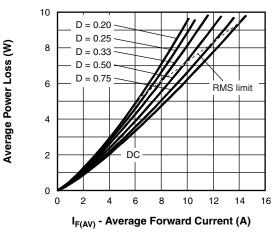


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

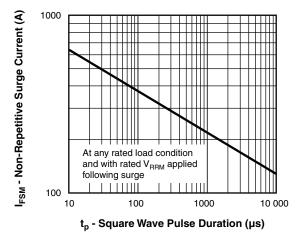


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

Note

- ⁽¹⁾ Formula used: $T_C = T_J (Pd + Pd_{REV}) \times R_{thJC}$;
- Pd = forward power loss = $I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 6); Pd_{REV} = inverse power loss = $V_{R1} \times I_R$ (1 - D); I_R at V_{R1} = rated V_R

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ORDERING INFORMATION TABLE

VISHA

Device code	VS-	MBR	20	100	СТ	-M3	
	1	2	3	4	5	6	
	1		,	niconduo BR serie		oduct	
	2 · 3 ·		,	ing (20			080 = 80 V
	4 · 5 ·		tage rati = esser	ngs – itial part	numbe	r	090 = 90 V 100 = 100 V
	6			ntal digit		L	

-M3 = halogen-free, RoHS-compliant, and termination lead (Pb)-free

ORDERING INFORMATION (Example)					
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION			
VS-MBR2080CT-M3	50	Antistatic plastic tubes			
VS-MBR2090CT-M3	50	Antistatic plastic tubes			
VS-MBR20100CT-M3	50	Antistatic plastic tubes			

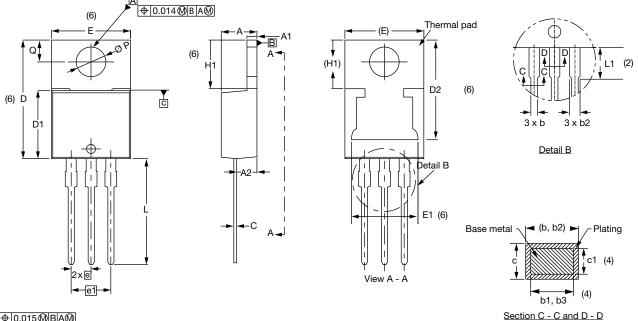
LINKS TO RELATED DOCUMENTS				
Dimensions www.vishay.com/doc?96154				
Part marking information	www.vishay.com/doc?95028			



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TO-220AB 3L

DIMENSIONS in millimeters and inches



⊕0.015@BA@



SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STINDUL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.50	2.92	0.098	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
С	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.35	0.585	0.604	3
D1	8.38	9.02	0.330	0.355	

MILLIMETERS	INCHES

Conforms to JEDEC[®] outline TO-220AB

SYMBOL			INCOLEO		NOTES
STIVIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
D2	11.68	13.30	0.460	0.524	6, 7
E	10.11	10.51	0.398	0.414	3, 6
E1	6.86	8.89	0.270	0.350	6
е	2.41	2.67	0.095	0.105	
e1	4.88	5.28	0.192	0.208	
H1	6.09	6.48	0.240	0.255	6
L	13.52	14.02	0.532	0.552	
L1	3.32	3.82	0.131	0.150	2
ØР	3.54	3.91	0.139	0.154	
Q	2.60	3.00	0.102	0.118	

Notes

 $^{(1)}\,$ Dimensioning and tolerancing as per ASME Y14.5M-1994

⁽²⁾ Lead dimension and finish uncontrolled in L1

(3) Dimension D, D1, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

⁽⁴⁾ Dimension b1, b3, and c1 apply to base metal only

(5) Controlling dimensions: inches

⁽⁶⁾ Thermal pad contour optional within dimensions E, H1, D2, and E1

⁽⁷⁾ Outline conforms to JEDEC[®] TO-220, except D2

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